

## **Electronic Correlation in Anion $p$ Orbitals Impedes Ferromagnetism**

The results of the present calculations for  $V^0$  are summarized in Table I.

**The complex energy surface of  $V^0$ .**—Because of a Jahn-Teller distortion, the symmetry of  $V^0$  is reduced to  $C_{2v}$  in the insulating phase, as schematically illustrated in Fig. 2. The distances of the ligand anions from the vacancy center for the lowest energy configurations of  $V^0$  are given in Table I. While standard LDA or GGA calculations do find a spin-polarized vacancy state for the case of the more localized 2p orbitals of ZnO [9

vacancy introduces two holes in a non-spin-polarized  $t_2$  symmetric state at the top of the ZnTe valence band, and conserves the tetrahedral ( $T_d$ ) point group symmetry. The band-structure character of the host  $\text{ZnTe}$  vacancy system is that of a non-spin-polarized metal [Fig. 1(a)]. However, the results obtained with the hole-state potential  $V_{\text{h}}$  draw an entirely different physical picture: As shown in Fig. 1(b), the previously non-spin-polarized and partially filled  $t_2$  symmetric band at the Fermi level [see Fig. 1(a)] now becomes spin polarized where the majority spin direction is fully occupied ( $a_p^1 t_p^3$ ), and the minority spin accommodates the two holes ( $a^1 t^1$ ), leading to a high-spin (HS,  $S = 1$ ) state. More importantly, the minority  $t$  level splits further into one lower-energy occupied and two higher-energy unoccupied subbands (i.e., lower and upper Hubbard bands), thereby opening a gap, in direct analogy to the Mott transition [Fig. 1(b)]. A low-spin (LS,  $S = 0$ ) state with a  $a_p^1 a^1 t_p^2 t^2$  configuration, which is also insulating, lies only slightly higher in energy. (For ZnO, ZnS, and ZnSe, GGA finds a spin-polarized state of  $V^0$ , but the level splitting occurs only in the presence of the potential  $V_{\text{h}}$ .)

So far, we discussed only the charge neutral state  $V^0$

experiences similar difficulties as in case of the cation vacancy pair interaction.

Regarding the magnetic coupling between NN pairs of vacancies, we face here a much more complex situation than in conventional systems, like GaAs:Mn, where one needs to compare only two (FM and AF) configurations. Since, as illustrated in Fig. 4, the two vacancies on the cation sublattice share a common anion that mediates the magnetic interaction between the vacancies, one might rather view the NN vacancy pair as a single entity, where there are four holes that can be distributed over seven ligands, and the spin configurations can couple to a total spin of  $S$